



Frontier Electronics Corp.

667 E. COCHRAN STREET, SIMI VALLEY, CA 93065

TEL: (805) 522-9998 FAX: (805) 522-9989

E-mail: frontiersales@frontierusa.com

Web: <http://www.frontierusa.com>

1A SURFACE MOUNT SUPER FAST RECOVERY RECTIFIERS

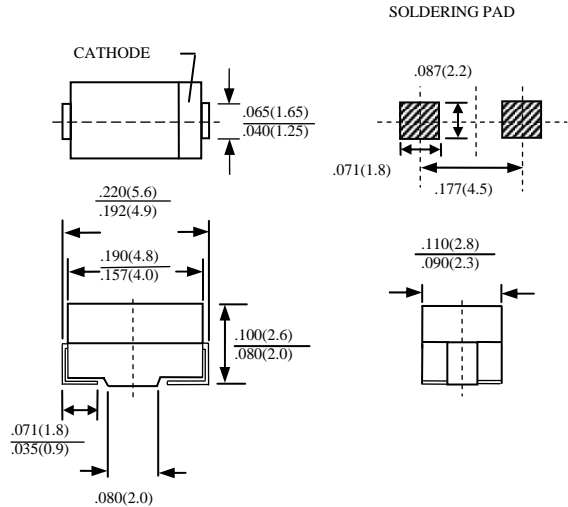
SFS1A-LFR THRU SFS1J-LFR

FEATURES

- FOR SURFACE MOUNTED APPLICATIONS
- LOW PROFILE PACKAGE
- BUILT-IN STRAIN RELIEF
- EASY PICK AND PLACE
- PLASTIC MATERIAL USED CARRIES UNDERWRITERS
LABORATORY CLASSIFICATION 94 V-0
- SUPER FAST SWITCHING
- GLASS PASSIVATED CHIP JUNCTION
- HIGH TEMPERATURE SOLDERING: 250°C /10 SECONDS AT TERMINALS
- ROHS

MECHANICAL DATA

- CASE: MOLDED PLASTIC, DO-214AC (SMA), DIMENSIONS IN INCHES AND (MILLIMETERS)
- TERMINALS: SOLDER PLATED
- POLARITY: INDICATED BY CATHODE BAND
- WEIGHT: 0.064 GRAMS



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS RATINGS AT 25°C AMBIENT TEMPERATURE UNLESS OTHERWISE SPECIFIED SINGLE PHASE, HALF WAVE, 60 HZ, RESISTIVE OR INDUCTIVE LOAD. FOR CAPACITIVE LOAD, DERATE CURRENT BY 20%

RATINGS	SYMBOL	SFS1A -LFR	SFS1B -LFR	SFS1D -LFR	SFS1E -LFR	SFS1G -LFR	SFS1H -LFR	SFS1J -LFR	UNITS
MAXIMUM RECURRENT PEAK REVERSE VOLTAGE	V_{RRM}	50	100	200	300	400	500	600	V
MAXIMUM RMS VOLTAGE	V_{RMS}	35	70	140	210	280	350	420	V
MAXIMUM DC BLOCKING VOLTAGE	V_{DC}	50	100	200	300	400	500	600	V
MAXIMUM AVERAGE FORWARD RECTIFIED CURRENT AT $T_L=90^\circ\text{C}$	I_O	1.0							A
MAXIMUM OVERLOAD SURGE 8.3ms SINGLE HALF SINE-WAVE	I_{FSM}	30							A
TYPICAL JUNCTION CAPACITANCE (NOTE 1)	C_j	15			10				PF
TYPICAL THERMAL RESISTANCE (NOTE 2)	θ_{JL}	30							$^\circ\text{C}/\text{W}$
STORAGE TEMPERATURE RANGE	T_{STG}	-55 TO + 150							$^\circ\text{C}$
OPERATING TEMPERATURE RANGE	T_{OP}	-55 TO + 125							$^\circ\text{C}$

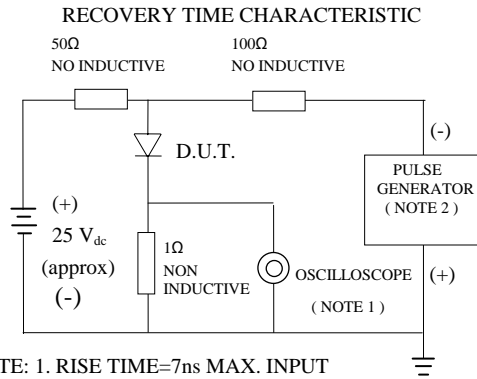
ELECTRICAL CHARACTERISTICS ($A_T T_A = 25^\circ\text{C}$ UNLESS OTHERWISE NOTED)

CHARACTERISTICS	SYMBOL	SFS1A -LFR	SFS1B -LFR	SFS1D -LFR	SFS1E -LFR	SFS1G -LFR	SFS1H -LFR	SFS1J -LFR	UNITS
MAXIMUM FORWARD VOLTAGE AT 1.0A AND 25°C	V_F	0.95			1.25		1.85		V
MAXIMUM REVERSE CURRENT AT 25°C	I_R	10							μA
MAXIMUM REVERSE RECOVERY TIME (NOTE 3)	T_{RR}	35							nS
MARKING		SF1A	SF1B	SF1D	SF1E	SF1G	SF1H	SF1J	

- NOTE:
1. MEASURED AT 1.0 MHZ AND APPLIED REVERSE VOLTAGE OF 4.0 V
 2. THERMAL RESISTANCE FROM JUNCTION TO TERMINAL 5.0mm² (.013 mm THICK) LAND AREAS
 3. REVERSE RECOVERY TEST CONDITIONS: $I_F=0.5\text{A}$, $I_R=1.0\text{A}$, $I_{RR}=0.25\text{A}$

RATINGS AND CHARACTERISTIC CURVE SFS1A-LFR THRU SFS1J-LFR

FIG. 1-TEST CIRCUIT DIAGRAM AND REVERSE



NOTE: 1. RISE TIME=7ns MAX. INPUT IMPEDANCE=1 MOhms 22PF
 2. RISE TIME =10ns MAX. SOURCE IMPEDANCE=50 OHMS

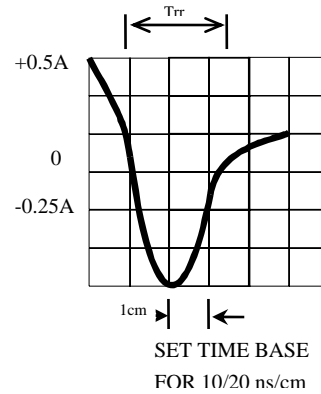


FIG. 2-TYPICAL FORWARD CURRENT DERATING CURVE

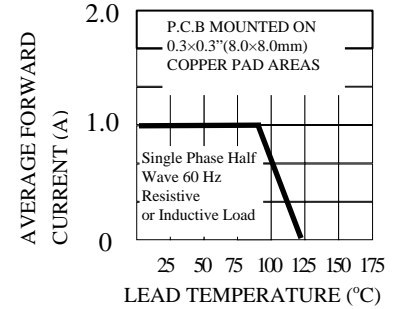


FIG. 3-TYPICAL REVERSE CHARACTERISTICS

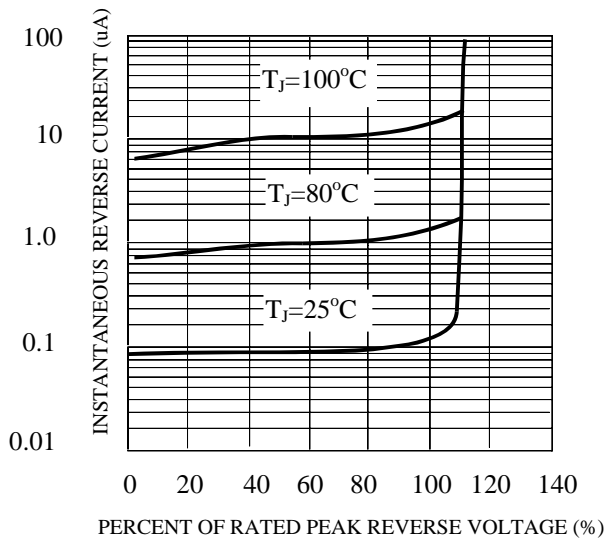


FIG. 4-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

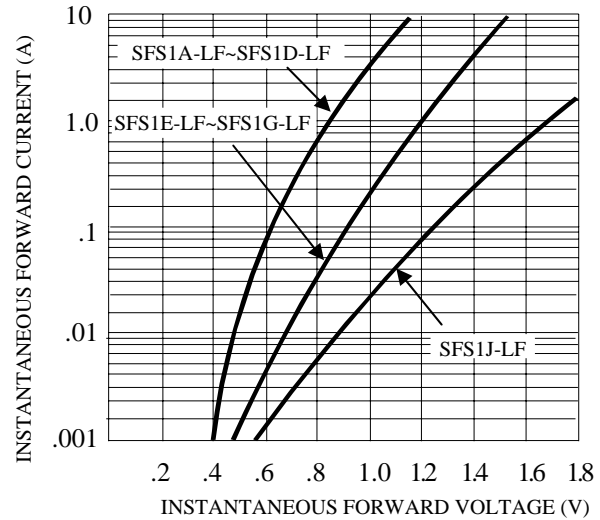


FIG. 5-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

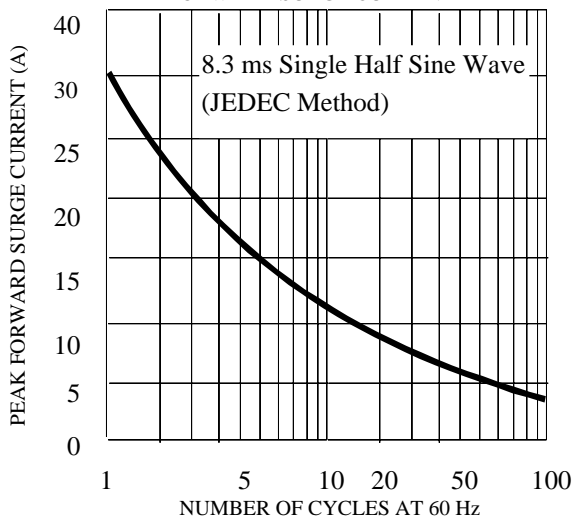


FIG. 6-TYPICAL JUNCTION CAPACITANCE

